Number	Hits	Search Text	DB USPAT;	Time stamp 2002/06/09 11:36
	892	semiconductor with nano\$7 and (dope doped)	US-PGPUB;	2002/00/05 11:50
			EPO; JPO;	
i			DERWENT	
			· I	2002/06/06 17:34
	139	semiconductor adj nanocrystal	USPAT;	2002/00/00 17.54
1			US-PGPUB;	
			EPO; JPO;	
1			DERWENT	2002/06/06 15:47
_	19	semiconductor adj nanocrystal with doped	USPAT;	2002/06/06 15:47
	.,	•	US-PGPUB;	
			EPO; JPO;	
			DERWENT	***********
	1	semiconductor adj nanocrystal and n-doped and p-doped	USPAT;	2002/06/06 16:04
-	•	John Commence of the Commence	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	,	semiconductor with nanocrystal and n-doped and p-doped	USPAT;	2002/06/06 16:04
-	2	Semiconductor with nanocrystal and it doped and p	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		doned and a doned	USPAT;	2002/06/06 16:04
-	3	semiconductor and nanocrystal and n-doped and p-doped	US-PGPUB;	
	i		EPO; JPO;	
			DERWENT	
	Ì		1	2002/06/06 16:0
-	3	semiconductor adj nanocrystal and p-doped	USPAT;	2002/00/00 10.0
			US-PGPUB;	
			EPO; JPO;	1
			DERWENT	000000000000000000000000000000000000000
	1	semiconductor adj nanocrystal and n-doped	USPAT;	2002/06/06 16:0
-	1	Someone and a series of	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	50	semiconductor adj nano\$7 and (dope doped)	USPAT;	2002/06/06 16:0
-	50	Semiconductor adj manos / and (dope dopes)	US-PGPUB;	i
			EPO; JPO;	
	Ì		DERWENT	
	ļ	ti da 1 (dans dans d) more? (n.n.)	USPAT;	2002/06/06 16:0
-	8	semiconductor adj nano\$7 and (dope doped) near2 (n p)	US-PGPUB;	
			EPO; JPO;	
	.		DERWENT	
	1	D. St. (testant hole)	USPAT;	2002/06/06 16:
-	8	semiconductor adj nanocrystal and (dope doped) with (electron hole)		2002/00/00 10.
	Į.		US-PGPUB;	
			EPO; JPO;	
			DERWENT	2002/06/06 16
_	12		USPAT;	2002/06/06 16:
	1	(dope doped) with (electron hole)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	*********
		(zinc adj oxide cadmium sulfide cadmium selenide) with nanocrystal and	USPAT;	2002/06/06 16:
•	1	(dope doped) with (electron hole)	US-PGPUB;	
		(dope doped) was (electron mass)	EPO; JPO;	
			DERWENT	
		(zinc adj oxide cadmium adj sulfide adj cadmium selenide) with	USPAT;	2002/06/06 16:
•	'	(zinc adj oxide cadmium adj suffice adj cadmium scientide) with nanocrystal and (dope doped) with (electron hole)	US-PGPUB;	
	İ	nanocrysiai and (dope doped) with (election note)	EPO; JPO;	
	ļ		DERWENT	1
	1	1 1 (1 da 1) with (alastron hole)	USPAT;	2002/06/06 16
-	3	nanocrystal and (dope doped) with (electron hole)	US-PGPUB;	l l
			EPO; JPO;	
,			DERWENT	2002/06/06 16
-		nanocrystal with (dope doped) with (electron hole)	USPAT;	i
			US-PGPUB	5
1			EPO; JPO;	
	1	I .	DERWENT	I

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			LICDATE	2002/06/06 16:21
-	0	nanocrystal with (dope doped) with (N-doped P-doped)	USPAT; US-PGPUB;	2002/06/06 16:21
			EPO; JPO;	
			DERWENT	
_ 1	0	nanocrystal with (N-doped P-doped)	USPAT;	2002/06/06 16:21
-		indicos) som (US-PGPUB;	
	Ì		EPO; JPO;	
			DERWENT	
		and and Ol daned D daned)	USPAT;	2002/06/06 16:22
-	10	nanocrystal and (N-doped P-doped)	US-PGPUB;	
			EPO; JPO;	
	1 1		DERWENT	
				2002/06/06 16:23
-	10	nanocrystal and (N-doped P-doped n-doped p-doped)	USPAT;	2002/00/00 10.23
	1		US-PGPUB;	
			EPO; JPO;	
	1		DERWENT	
_	241	nanocrystal and doped	USPAT;	2002/06/06 16:23
	1 - 7 1		US-PGPUB;	ı
			EPO; JPO;	
	1		DERWENT	
	.	nanocrystal with doped with (hole)	USPAT;	2002/06/06 16:24
-	1	nanocrystal with doped with (note)	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT	
	1			2002/06/06 16:24
-	28	nanocrystal with (hole)	USPAT;	2002/00/00 10.24
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
_	11	nanocrystal with (hole) and (zinc adj oxide cadmium adj selenide	USPAT;	2002/06/06 16:30
-	1	cadmium adj sulfide)	US-PGPUB;	
		outilities and outlier,	EPO; JPO;	
			DERWENT	
	1 24	dop\$3 with semiconductor near5 nanocrystal and (electron hole)	USPAT;	2002/06/06 16:37
-	24	dop53 with semiconductor near 5 harroerystar and (electron note)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	ļ
				2002/06/06 17:29
-	6	semiconductor near5 nanocrystal and (N near P) adj Junction	USPAT;	2002/00/00 17.25
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	8	(semiconductor adj nanocrystal) near dope?	USPAT;	2002/06/06 17:30
_			US-PGPUB;	
			EPO; JPO;	
	Ì		DERWENT	
		(semiconductor adj nanocrystal) near (n p)	USPAT;	2002/06/06 17:31
•	2	(Semiconductor adjuanocrystar) near (n p)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
			USPAT;	2002/06/06 17:31
-	0	(semiconductor adj nanocrystal) with n-doped		2002/00/00 17.5
			US-PGPUB;	
			EPO; JPO;	
	1		DERWENT	
_	0	(semiconductor adj nanocrystal) with p-doped	USPAT;	2002/06/06 17:3
	1		US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	,	(semiconductor adj nanocrystal) and n-doped	USPAT;	2002/06/06 17:3
-	1	(Schileonductor adj nanocrystar) and n-doped	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT	
				2002/06/06 17:3
-	3	(semiconductor adj nanocrystal) and p-doped	USPAT;	2002/00/00 17.5
			US-PGPUB;	
1	1		EPO; JPO;	
i			DERWENT	

	50	semiconductor adj nanocrystal and doped	USPAT;	2002/06/06 17:34
-	59	semiconductor adj nanocrystal and doped	US-PGPUB;	
			EPO; JPO;	
			DERWENT	i
		semiconductor adj nanocrystal and doped with (N-P)	USPAT;	2002/06/06 17:34
•	0	semiconductor adj francerystar and doped with (14.17)	US-PGPUB;	
3			EPO; JPO;	
	i		DERWENT	
	. [semiconductor adj nanocrystal and doped and (N-P)	USPAT;	2002/06/06 17:35
	1	semiconductor adj nanocrystal and doped and (14.1)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		semiconductor adj nanocrystal and doped and (oxidie oxidizing reduce	USPAT;	2002/06/06 17:35
	41		US-PGPUB;	1
	ļ 1	reducing)	EPO; JPO;	
			DERWENT	
	<u> </u>	semiconductor adj nanocrystal and doped and (oxidize oxidizing reduce	USPAT;	2002/06/06 17:55
-	41		US-PGPUB;	
	l l	reducing)	EPO; JPO;	
			DERWENT	
	1	the standard and electron and electrochemical	USPAT;	2002/06/06 17:56
-	2	semiconductor adj nanocrystal and hole and electron and electrochemical	US-PGPUB;	
	ł		EPO; JPO;	
			DERWENT	
		ti and halo and electron and	USPAT;	2002/06/06 17:58
-	2	semiconductor adj nanocrystal and hole and electron and	US-PGPUB;	
		electrochemical\$3	EPO; JPO;	1
			DERWENT	
	1		USPAT;	2002/06/06 18:06
•	21	"5537000"	US-PGPUB;	
			EPO; JPO;	
	ļ		DERWENT	
		and and doned electron adj doned	USPAT;	2002/06/06 18:07
-	1	"5537000" and (dope dopant n adj doped p adj doped electron adj doped	US-PGPUB;	
		hole adj doped)	EPO; JPO;	
	l l		DERWENT	
			USPAT;	2002/06/06 18:18
-	9	semiconductor with nanocrystal\$3 and (hole near5 doped electron near5	US-PGPUB;	
		doped)	EPO; JPO;	
			DERWENT	
		(Cadmium adj Sulfide Cadmium adj selenide CdS CdSe) and (hole near5	USPAT;	2002/06/06 18:10
-	339		US-PGPUB;	
	1	doped electron near5 doped)	EPO; JPO;	
			DERWENT	
	_	doped with nanocrystal\$3 and semiconductor and electrolyte	USPAT;	2002/06/06 18:21
·	3	doped with nanocrystalas and semiconductor and electrosyte	US-PGPUB;	
	Į.		EPO; JPO;	
	· [DERWENT	
	1	1155222771	USPAT;	2002/06/06 18:21
-	11	"5522377"	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		W. 70007771	USPAT;	2002/06/06 18:21
-	11	"5522377"	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT	
	1 .	0.00111005 md	USPAT;	2002/06/06 18:2
•		0 06111995.pd.	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		10000011 4	USPAT;	2002/06/06 18:2
-	220	0 19950611.pd.	US-PGPUB	"
			EPO; JPO;	
	- 1		DERWENT	
	l .			

	16465	19960611.pd.	USPAT; US-PGPUB;	2002/06/06 18:24
			EPO; JPO;	
			DERWENT	
	0	"encapsulated quantum sized doped semiconductor particles and method	USPAT;	2002/06/06 18:25
•		for making same".ti.	US-PGPUB;	
		for making same	EPO; JPO;	
			DERWENT	Į
	5	doped adj semiconductor adj particles.ti.	USPAT;	2002/06/06 18:39
		dopod adjoranicon voji	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	12	"6048616"	USPAT;	2002/06/06 18:33
	1		US-PGPUB;	
			EPO; JPO;	
			DERWENT	2002/06/06 18:33
-	3	("5525377").PN.	USPAT;	2002/00/00 18.33
			US-PGPUB; EPO; JPO;	
		•	DERWENT	
		P I'D	USPAT;	2002/06/06 18:39
•	31	semiconductor adj nanocrystal and IR	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT	
	1 4	semiconductor adj nanocrystal and infrared	USPAT:	2002/06/06 18:43
-	44	semiconductor adj nanocrystar and infrared	US-PGPUB;	
			EPO; JPO;	
	ļ		DERWENT	
	3	semiconductor adj nanocrystal and (n near p) adj junction	USPAT;	2002/06/06 18:46
•	3	Settineoridation adj nanoesystan and (ii nom p) maj james	US-PGPUB;	
			EPO; JPO;	
	ļ		DERWENT	
-	11	semiconductor adj nanocrystal and (n near p)	USPAT;	2002/06/06 18:46
-		,	US-PGPUB;	
	Ì		EPO; JPO;	
			DERWENT	2002/07/07 10:02
-	0	(N near P) adj junction and semicaonductor adj nanocrystal	USPAT;	2002/06/07 10:03
			US-PGPUB;	
			EPO; JPO;	
			DERWENT USPAT;	2002/06/07 10:06
-	3	(N near P) adj junction and semiconductor adj nanocrystal	US-PGPUB;	2002/00/07 10:00
			EPO; JPO;	
			DERWENT	
		(N near P) adj junction and semiconductor adj nanocrystal and electrolyte	USPAT;	2002/06/07 10:07
-	1	(IN near F) and junction and semiconductor and manoery star and electrosystems	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	1	(N near P) adj junction and semiconductor with nanocrystal and	USPAT;	2002/06/07 10:31
•	1	electrolyte	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	1	(N near P) with junction and semiconductor with nanocrystal and	USPAT;	2002/06/07 10:36
		electrolyte	US-PGPUB;	
			EPO; JPO;	1
			DERWENT	2002/06/07 10:38
-	2	(N near P) with junction and nanocrystal and electrolyte	USPAT;	2002/00/07 10.30
			US-PGPUB; EPO; JPO;	
			DERWENT	
	1	the state of the s	USPAT;	2002/06/07 10:39
	4	semiconductor adj nanocrystal and electrolyte	US-PGPUB;	2002/00/07 10:5
•				
-			EPO; JPO;	

<u> </u>	6	semiconductor near5 nanocrystal and electrolyte	USPAT;	2002/06/07 10:39
	1	•	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
_		semiconductor near5 nanocrystal and polyethylene adj oxide	USPAT;	2002/06/07 10:57
-	1 1	, , ,	US-PGPUB;	
		•	EPO; JPO;	
	. 1		DERWENT	
	17	(n near p) near5 junction and nanocrystal	USPAT;	2002/06/07 11:05
-	1 1	(If float p) float of Janobian and Janobian	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	0	junction with nanocrystal with (CdS CdSe)	USPAT;	2002/06/07 11:05
-	0	Junction with handery star with (eds edse)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		junction with nanocrystal with semiconductor	USPAT;	2002/06/07 11:06
-	3	junction with nanocrystal with semiconductor	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		A continuation	USPAT;	2002/06/07 11:07
-	21467	(n near p) near junction	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		901 11 010 C 1 iii m 4		2002/06/07 11:55
-	1238	(n near p) near junction and (Cadmium adj Selenide CdSe Cadmium adj	USPAT;	2002/00/07 11.55
		Sulfide CdS)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	2002/06/07 11.55
-	0	(n near p) near junction and (Cadmium adj Selenide CdSe Cadmium adj	USPAT;	2002/06/07 11:55
		Sulfide CdS) with nano	US-PGPUB;	
		,	EPO; JPO;	
			DERWENT	
_	136	(n near p) near junction and (Cadmium adj Selenide CdSe Cadmium adj	USPAT;	2002/06/07 12:01
-	.50	Sulfide CdS) with crystal	US-PGPUB;	
	1	(Camaba (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba) (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba) (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba) (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba) (Camaba (Camaba (Camaba (Camaba (Camaba (Camaba (Camab	EPO; JPO;	
			DERWENT	
	5	semiconductor with nanocrystal and memory adj array and doped	USPAT;	2002/06/07 12:01
•		Schillondactor with hands your and	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	10	(n near p) near junction and (Cadmium adj Selenide CdSe Cadmium adj	USPAT;	2002/06/07 12:06
-	19		US-PGPUB;	
		Sulfide CdS) with quantum	EPO; JPO;	
			DERWENT	
		semiconductor with nanocrystal with doped and memory	USPAT;	2002/06/07 12:03
-	4	semiconductor with nanocrystal with doped and memory	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
		to the set of Continue at Colonida Cala Cadmium adi	USPAT;	2002/06/07 12:44
-	18	(n near p) near junction and (Cadmium adj Selenide CdSe Cadmium adj	US-PGPUB;	2002/00/01 12:11
		Sulfide CdS) with particles	EPO; JPO;	
			DERWENT	
				2002/06/07 12:46
•	6	poly near5 paraphenylene and polymer adj electrolyte	USPAT;	2002/00/07 12.40
			US-PGPUB;	
	1		EPO; JPO;	
			DERWENT	2002/04/07 12:44
-	0	poly near5 paraphenylene with polymer adj electrolyte	USPAT;	2002/06/07 12:45
			US-PGPUB;	
	ļ		EPO; JPO;	
			DERWENT	************
-	0	poly near5 paraphenylene with electrolyte	USPAT;	2002/06/07 12:4:
}			US-PGPUB;	
1			EPO; JPO;	
Į.	1		DERWENT	

•	20	poly near5 paraphenylene and polymer with electrolyte	USPAT; US-PGPUB;	2002/06/07 12:47
			EPO; JPO;	
			DERWENT	
-	0	poly near5 paraphenylene with polyethylene adj oxide and display	USPAT;	2002/06/07 12:48
			US-PGPUB;	
			EPO; JPO;	
		ADV. MADEO. 11' 1	DERWENT	2002/06/07 12:50
-	3	PPV with PEO and display	USPAT; US-PGPUB;	2002/06/07 12:50
į			EPO; JPO;	
			DERWENT	
_	6953	polymer adj electrolyte	USPAT;	2002/06/07 12:50
	0,55	polymor adj oteracija	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
_	0	polymer adj electrolyte with PPV	USPAT;	2002/06/07 12:50
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	2002/06/07 12 55
-	9	polymer adj electrolyte and paraphenylene	USPAT;	2002/06/07 12:52
			US-PGPUB;	
			EPO; JPO;	
	2	polymer adj electrolyte and paraphenylene and display	DERWENT USPAT;	2002/06/07 12:53
-	2	polymer and electrolyte and paraphenytene and display	US-PGPUB;	2002/00/07 12.33
			EPO; JPO;	
			DERWENT	
-	14	electrolyte and paraphenylene and display	USPAT;	2002/06/07 12:54
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
-	193	(polyethyleneoxide polyethylen adj oxide) and display	USPAT;	2002/06/07 12:55
			US-PGPUB;	
			EPO; JPO; DERWENT	
	2381	(polyethyleneoxide polyethylene adj oxide) and display	USPAT;	2002/06/07 12:55
-	2381	(polyethyleneoxide polyethylene adj oxide) and display	US-PGPUB;	2002/00/07 12.33
			EPO; JPO;	
			DERWENT	*
_	1	(polyethyleneoxide polyethylen adj oxide) and semiconductor adj	USPAT;	2002/06/07 12:56
		nanocrystal	US-PGPUB;	
			EPO; JPO;	
		<u> </u>	DERWENT	2002/06/05 12 55
-	0	(polyethyleneoxide polyethylen adj oxide) with nanocrystal	USPAT;	2002/06/07 12:55
			US-PGPUB;	
			EPO; JPO; DERWENT	
_	3	(polyethyleneoxide polyethylene adj oxide) with nanocrystal	USPAT;	2002/06/07 12:55
-		(poryoniyionoonide poryoniyione daj onide) with hanoorystal	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
-	2	(polyethyleneoxide polyethylene adj oxide) and semiconductor adj	USPAT;	2002/06/07 12:56
		nanocrystal	US-PGPUB;	
			EPO; JPO;	
			DERWENT	2002/06/00 11 26
-	216	n-type with Cadmium adj sulfide	USPAT;	2002/06/09 11:36
			US-PGPUB;	
			EPO; JPO; DERWENT	
1_	32	n-type with Cadmium adj sulfide with (copper manganese)	USPAT;	2002/06/09 11:37
] -	32	in-type with Cadmain adj surface with (copper manganese)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	

	0	n-type with Cadmium adj selenide with (copper manganese)	USPAT;	2002/06/09 11:37
		, a de la company de la compan	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
-	17	n-type and Cadmium adj selenide with (copper manganese)	USPAT;	2002/06/09 11:51
			US-PGPUB;	
	1		EPO; JPO;	
			DERWENT	
-	55	n-type with manganese	USPAT;	2002/06/09 11:52
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	2002/06/00 12:07
ļ -	711	cadmium adj sulfide and n-type	USPAT; US-PGPUB;	2002/06/09 12:07
İ			EPO; JPO;	
			DERWENT	İ
	216	Indiana - It materials with mittens	USPAT;	2002/06/09 12:15
-	216	cadmium adj sulfide with n-type	US-PGPUB;	2002,00,00
			EPO; JPO;	
			DERWENT	
	663	doping with (hole and electron)	USPAT;	2002/06/09 12:15
		gobing with (got min steemen)	US-PGPUB;	
1			EPO; JPO;	
	Ì		DERWENT	